NSN 5961-01-059-1222

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-059-1222 **Inclosure Material:** Plastic **Overall Length:** Between 0.580 inches and 0.620 inches **Overall Height:** Between 0.170 inches and 0.196 inches Overall Width: Between 0.515 inches and 0.535 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Internal Junction Configuration:** Npn **Mounting Method:** Bracket and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 3.0 base to emitter voltage, dc and 60.0 breakdown voltage, collector-to-emitter, base open and 60.0 collector to base voltage, dc and 50.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 2.00 milliamperes zero-gate-voltage source current absolute and 1.00 milliamperes zero-gate-voltage source current preset and 2.00 milliamperes zero-gate-voltage source current major **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No